M1MA151WKT1, M1MA152WKT1

Preferred Device

Common Cathode Silicon Dual Switching Diodes

These Common Cathode Silicon Epitaxial Planar Dual Diodes are designed for use in ultra high speed switching applications. These devices are housed in the SC-59 package which is designed for low power surface mount applications.

- Fast t_{rr} , < 3.0 ns
- Low C_D , < 2.0 pF
- Available in 8 mm Tape and Reel
 Use M1MA151/2WKT1 to order the 7 inch/3000 unit reel.
- Pb-Free Packages are Available

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit	
Reverse Voltage	M1MA151WKT1	V_R	40	Vdc
	M1MA152WKT1		80	
Peak Reverse Voltage	M1MA151WKT1	V_{RM}	40	Vdc
	M1MA152WKT1	1	80	
Forward Current	Single	I _F	100	mAdc
	Dual	1	150	
Peak Forward Current	Single	I _{FM}	225	mAdc
	Dual	1	340	
Peak Forward Surge	Single	I _{FSM}	500	mAdc
Current	Dual	(Note 1)	750	

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation	P _D	200	mW
Junction Temperature	T_J	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

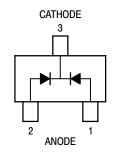
1. t = 1 SEC



ON Semiconductor®

http://onsemi.com

SC-59 PACKAGE SINGLE SILICON SWITCHING DIODES 40 V/80 V 100 mA SURFACE MOUNT





SC-59 CASE 318D



MARKING

x = T for 151 U for 152 M = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
M1MA151WKT1	SC-59	3000 / Tape & Reel
M1MA151WKT1G	SC-59 (Pb-Free)	3000 / Tape & Reel
M1MA151WKT1	SC-59	3000 / Tape & Reel
M1MA151WKT1G	SC-59 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

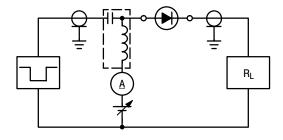
M1MA151WKT1, M1MA152WKT1

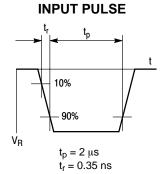
ELECTRICAL CHARACTERISTICS $(T_A = 25^{\circ}C)$

Characteristic		Symbol	Condition	Min	Max	Unit
Reverse Voltage Leakage Current	M1MA151WKT1	I _R	V _R = 35 V	_	0.1	μAdc
	M1MA152WKT1		V _R = 75 V	_	0.1	
Forward Voltage	•	V _F	I _F = 100 mA	_	1.2	Vdc
Reverse Breakdown Voltage	M1MA151WKT1	V_{R}	I _R = 100 μA	40	_	Vdc
	M1MA152WKT1			80	_	
Diode Capacitance		C _D	V _R = 0, f = 1.0 MHz	_	2.0	pF
Reverse Recovery Time (Figure 1)		t _{rr} (Note 2)	$I_F = 10 \text{ mA}, V_R = 6.0 \text{ V},$ $R_L = 100 \Omega, I_{rr} = 0.1 I_R$	ı	3.0	ns

^{2.} t_{rr} Test Circuit

RECOVERY TIME EQUIVALENT TEST CIRCUIT





OUTPUT PULSE

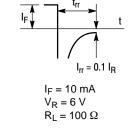
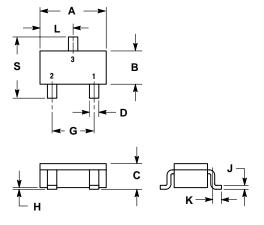


Figure 1. Reverse Recovery Time Equivalent Test Circuit

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PACKAGE DIMENSIONS

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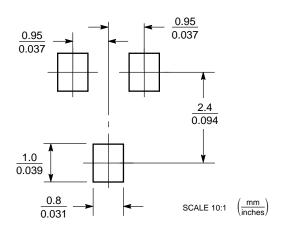


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	2.70	3.10	0.1063	0.1220
В	1.30	1.70	0.0512	0.0669
C	1.00	1.30	0.0394	0.0511
D	0.35	0.50	0.0138	0.0196
G	1.70	2.10	0.0670	0.0826
Н	0.013	0.100	0.0005	0.0040
7	0.09	0.18	0.0034	0.0070
K	0.20	0.60	0.0079	0.0236
L	1.25	1.65	0.0493	0.0649
S	2.50	3.00	0.0985	0.1181

STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

M1MA151WKT1, M1MA152WKT1

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